

# AOS Semiconductor Product Reliability Report

## AO4405/AO4405L, rev D

**Plastic Encapsulated Device** 

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Mar 6, 2008



This AOS product reliability report summarizes the qualification result for AO4405. Accelerated environmental tests are performed on a specific sample size, and then followed by electrical test at end point. Review of final electrical test result confirms that AO4405 passes AOS quality and reliability requirements. The released product will be categorized by the process family and be monitored on a quarterly basis for continuously improving the product quality.

#### **Table of Contents:**

- I. Product Description
- II. Package and Die information
- III. Environmental Stress Test Summary and Result
- IV. Reliability Evaluation
- V. Quality Assurance Information

#### I. Product Description:

The AO4405 uses advanced trench technology to provide excellent  $R_{DS(ON)}$  with low gate charge. This device is suitable for use as a load switch or in PWM applications. Standard product AO4405 is Pb-free (meets ROHS & Sony 259 specifications).

| <b>Absolute Maximum</b>                            | Ratings T <sub>A</sub> | =25°C unless othe | rwise noted |       |  |
|--|------------------------|-------------------|-------------|-------|--|
| Parameter Drain-Source Voltage Gate-Source Voltage |                        | Symbol            | Maximum     | Units |  |
|  |                        | $V_{DS}$          | -30         | V     |  |
|  |                        | $V_{GS}$          | ±20         | V     |  |
| Continuous Drain                                   | T <sub>A</sub> =25°C   |                   | -6          |       |  |
| Current  | T <sub>A</sub> =70°C   | I <sub>D</sub>    | -5.1        | Α     |  |
| Pulsed Drain Current                               |                        | I <sub>DM</sub>   | -30         |       |  |
|  | T <sub>A</sub> =25°C   | P <sub>D</sub>    | 3           | W     |  |
| Power Dissipation T <sub>A</sub> =70°              |                        | I D               | 2.1         |       |  |
| Junction and Storage<br>Temperature Range          |                        | Tı, Teta          | -55 to 150  | °C    |  |

| Thermal Characteristics         |                  |                                   |     |       |      |  |
|---------------------------------|------------------|-----------------------------------|-----|-------|------|--|
| Parameter                       | Symbol           | Тур                               | Max | Units |      |  |
| Maximum Junction-to-<br>Ambient | t ≤ 10s          | Б                                 | 31  | 40    | °C/W |  |
| Maximum Junction-to-<br>Ambient | Steady-<br>State | $R_{	ext{	heta}JA}$               | 59  | 75    | °C/W |  |
| Maximum Junction-to-Lead        | Steady-<br>State | $R_{\scriptscriptstyle{	hetaJL}}$ | 16  | 24    | °C/W |  |



#### II. Die / Package Information:

AO4405 AO4405L (Green Compound)

ProcessStandard sub-micronStandard sub-micron

Low voltage P channel process Low voltage P channel process

Package Type8 leads SOIC8 leads SOICLead FrameCu, S/pad, Ag spotCu, S/pad, Ag spot

Die AttachAg epoxyAg epoxyBond wireAu 2milsAu 2 mils

Mold Material Epoxy resin with silica filler Epoxy resin with silica filler

Filler % (Spherical/Flake)90/10100/0Flammability RatingUL-94 V-0UL-94 V-0Backside MetallizationTi / Ni / AgTi / Ni / AgMoisture LevelUp to Level 1 \*Up to Level 1\*

Note \* based on info provided by assembler and mold compound supplier

#### III. Result of Reliability Stress for AO4405 (Standard) & AO4405L (Green)

| Test Item                        | Test Condition   | Time<br>Point                | Lot Attribution                                   | Total<br>Sample<br>size       | Number<br>of<br>Failures |
|----------------------------------|--|------------------------------|---|-------------------------------|--------------------------|
| Solder<br>Reflow<br>Precondition | Standard: 1hr PCT+3<br>cycle reflow@260°c<br>Green: 168hr 85°c<br>/85%RH+3 cycle<br>reflow@260°c | Ohr                          | Standard: 83 lots<br>Green: 29 lots               | 17380 pcs                     | 0                        |
| HTGB                             | Temp = 150°c ,<br>Vgs=100% of Vgsmax   | 168 / 500<br>hrs<br>1000 hrs | 3 lots<br>(Note A*)                               | 246 pcs<br>77+5 pcs /<br>lot  | 0                        |
| HTRB                             | Temp = 150°c ,<br>Vds=80% of Vdsmax  | 168 / 500<br>hrs<br>1000 hrs | 3 lots<br>(Note A*)                               | 246 pcs<br>77+5 pcs /<br>lot  | 0                        |
| HAST                             | 130 +/- 2 c , 85%RH,<br>33.3 psi, Vgs = 80% of<br>Vgs max  | 100 hrs                      | Standard: 81 lots<br>Green: 16 lots<br>(Note B**) | 5335 pcs<br>50+5 pcs /<br>lot | 0                        |
| Pressure Pot                     | 121 <sup>-</sup> c , 29.7psi,<br>RH=100%   | 96 hrs                       | Standard: 83 lots<br>Green: 20 lots<br>(Note B**) | 5665 pcs<br>50+5 pcs /<br>lot | 0                        |
| Temperature<br>Cycle             | -65°c to 150°c,<br>air to air,   | 250 / 500<br>cycles          | Standard: 87 lots<br>Green: 29 lots<br>(Note B**) | 6380 pcs<br>50+5 pcs /<br>lot | 0                        |



## III. Result of Reliability Stress for AO4405 (Standard) & AO4405L (Green) Continues

| DPA            | Internal Vision<br>Cross-section<br>X-ray | NA                    | 5<br>5<br>5    | 5<br>5<br>5                      | 0 |
|----------------|---|-----------------------|----------------|----------------------------------|---|
| CSAM           |   | NA                    | 5              | 5                                | 0 |
| Bond Integrity | Room Temp<br>150°c bake<br>150°c bake     | 0hr<br>250hr<br>500hr | 40<br>40<br>40 | 40 wires<br>40 wires<br>40 wires | 0 |
| Solderability  | 245°C                                     | 5 sec                 | 15             | 15 leads                         | 0 |
|                |   |                       |                |                                  |   |

**Note A:** The HTGB and HTRB reliability data presents total of available AO4405 and AO4405L burn-in data up to the published date.

**Note B:** The pressure pot, temperature cycle and HAST reliability data for AO4405 and AO4405L comes from the AOS generic package qualification data.

#### IV. Reliability Evaluation

FIT rate (per billion): 14.4 MTTF = 7927 years

In general, 500 hrs of HTGB, 150 deg C accelerated stress testing is equivalent to 15 years of lifetime at 55 deg C operating conditions (by applying the Arrhenius equation with an activation energy of 0.7eV and 60% of upper confidence level on the failure rate calculation). AOS reliability group also routinely monitors the product reliability up to 1000 hr at and performs the necessary failure analysis on the units failed for reliability test(s).

The presentation of FIT rate for the individual product reliability is restricted by the actual burn-in sample size of the selected product (AO4405). Failure Rate Determination is based on JEDEC Standard JESD 85. FIT means one failure per billion hours.

**Failure Rate** =  $\text{Chi}^2 \times 10^9 / [2 \text{ (N) (H) (Af)}] = 1.83 \times 10^9 / [2 (3 \times 164) (500) (258)] = 14.4 \text{ MTTF} = <math>10^9 / \text{FIT} = 6.94 \times 10^7 \text{hrs} = 7927 \text{years}$ 

**Chi**<sup>2</sup> = Chi Squared Distribution, determined by the number of failures and confidence interval **N** = Total Number of units from HTRB and HTGB tests

**H** = Duration of HTRB/HTGB testing

Af = Acceleration Factor from Test to Use Conditions (Ea = 0.7eV and Tuse = 55°c)

Acceleration Factor [Af] = Exp [Ea / k (1/Tj u - 1/Tj s)]

**Acceleration Factor ratio list:** 

| 7.000.0 |          |          |          |           |           |           |           |
|---------|----------|----------|----------|-----------|-----------|-----------|-----------|
|         | 55 deg C | 70 deg C | 85 deg C | 100 deg C | 115 deg C | 130 deg C | 150 deg C |
| Af      | 258      | 87       | 32       | 13        | 5.64      | 2.59      | 1         |

Tj s = Stressed junction temperature in degree (Kelvin), K = C+273.16

Tj u =The use junction temperature in degree (Kelvin), K = C+273.16

**k** = Boltzmann's constant, 8.617164 X 10<sup>-5</sup>eV / K



### V. Quality Assurance Information

Acceptable Quality Level for outgoing inspection: **0.1%** for electrical and visual. Guaranteed Outgoing Defect Rate: **< 25 ppm** Quality Sample Plan: conform to **Mil-Std-105D**